MSKSEMI















ESD

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PLED

Broduct data sheet







S0D-123FL



Applications

General rectification

Features

- Small power mold type.(PMDU)
- Low I_R.
- High reliability.

Construction

Silicon epitaxial planar

Absolute maximum ratings (Ta=25°C)

| Parameter | Symbol | Limits | Unit |
|--|------------------|-------------|------|
| Reverse voltage (repetitive peak) | V_{RM} | 60 | V |
| Reverse voltage (DC) | VR | 60 | V |
| Average rectified forward current | lo | 1 | Α |
| Forward current surge peak (60Hz · 1cyc) | I _{FSM} | 30 | Α |
| Junction temperature | Tj | 150 | °C |
| Storage temperature | Tstg | -40 to +150 | °C |

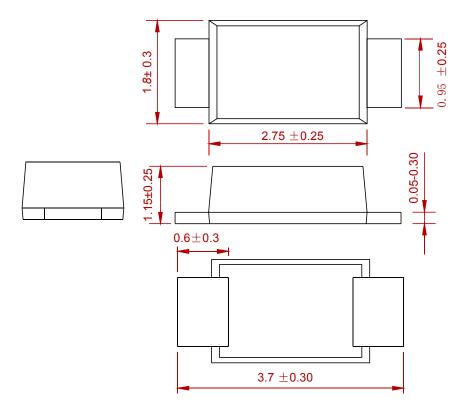
^(*1)Mounted on epoxy board. 180°Half sine wave

Electrical characteristics (Ta=25°C)

| Parameter | Symbol | Min. | Тур. | Max. | Unit | Conditions |
|-----------------------|----------------|------|------|------|------|------------------------------|
| Forward voltage | VF | - | 0.49 | 0.55 | V | I _F =1.0A |
| Reverse current | I _R | - | 7.0 | 50 | μA | V _R =60V |
| Capacitance terminals | Ct | - | 40 | - | pF | V _R =10V , f=1MHz |

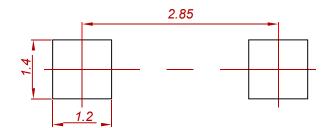


PACKAGE MECHANICAL DATA



Dimensions in millimeters

Suggested Pad Layout



Note:

- 1. Controlling dimension:in millimeters.
- 2.General tolerance:±0.05mm.
- 3. The pad layout is for reference purposes only.

REEL SPECIFICATION

| P/N | PKG | QTY |
|-----------|-----------|------|
| RB160M-60 | SOD-123FL | 3000 |



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